

Highly Granular Crystal Calorimeter: Development Status

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On behalf of CEPC Calorimeter Working Group

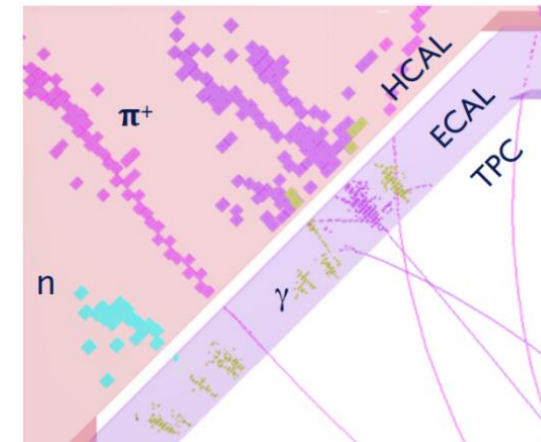
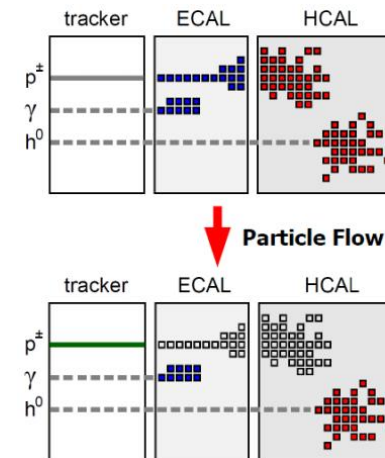
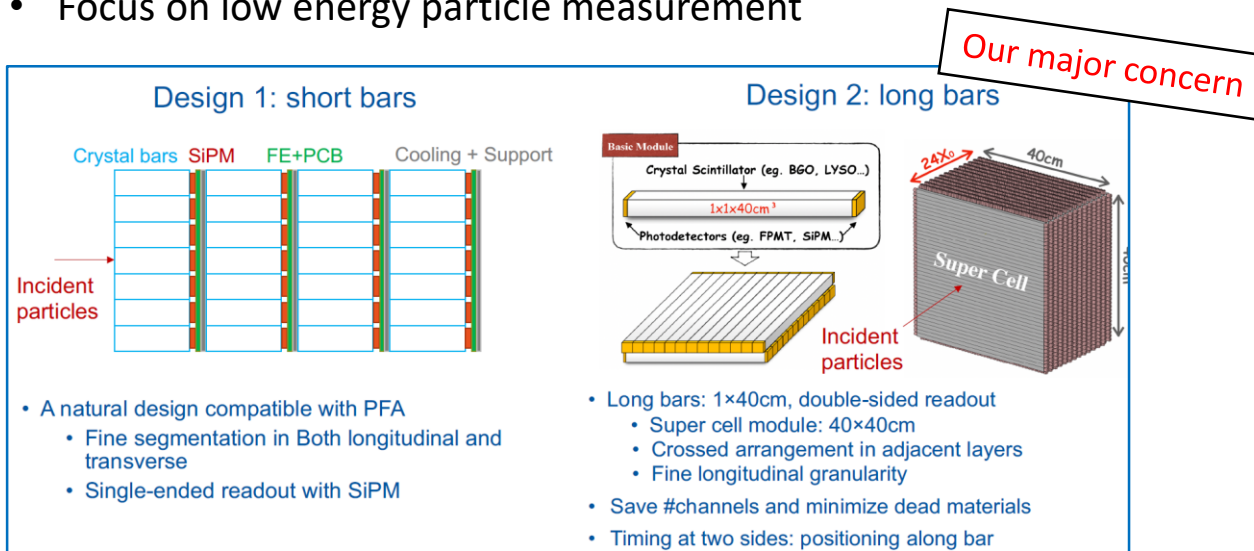
CEPC Physics and Detector Plenary Meeting

April 20, 2022

Motivations

- Background: calorimeter for future lepton colliders (e.g. CEPC)
 - Precision measurements with Higgs and Z/W
 - Jet energy resolution of 3-4% @ 100 GeV is required
 - Particle flow approach: high-granularity calorimeter
- Why crystal calorimeter?
 - Homogeneous structure
 - Intrinsic energy resolution: $\sim 3\%/\sqrt{E} \oplus \sim 1\%$
 - Energy recovery of electrons: to improve Higgs recoil mass
 - Capability to trigger single photons: precision γ/π^0 reconstruction
 - Focus on low energy particle measurement

Physics process	Measurands	Critical detector	Required performance
$ZH \rightarrow l^+l^-X$	m_H, σ_{ZH}	Tracker	$\Delta(1/P_T) = 2 \times 10^{-5} \oplus \frac{10^{-3}}{p(\text{GeV})\sin^2\theta}$
$H \rightarrow \mu^+\mu^-$	$B(H \rightarrow \mu^+\mu^-)$		
$H \rightarrow b\bar{b}, c\bar{c}, gg$	$B(H \rightarrow b\bar{b}, c\bar{c}, gg)$	Vertex	$\sigma_{r,\phi} = 5 \oplus \frac{10}{p(\text{GeV})\sin^2\theta} (\mu\text{m})$
$H \rightarrow q\bar{q}, W^+W^-, ZZ$	$B(H \rightarrow q\bar{q}, W^+W^-, ZZ)$	Calo	$\sigma_E^{jet} = 3 \sim 4\% @ 100 \text{ GeV}$
$H \rightarrow \gamma\gamma$	$B(H \rightarrow \gamma\gamma)$	ECAL	$\frac{\Delta E}{E} = \frac{0.20}{\sqrt{E(\text{GeV})}} \oplus 0.01$

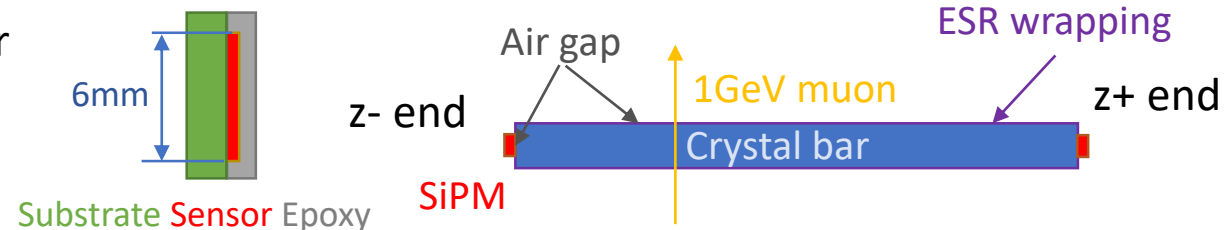


Development of crystal ECAL:

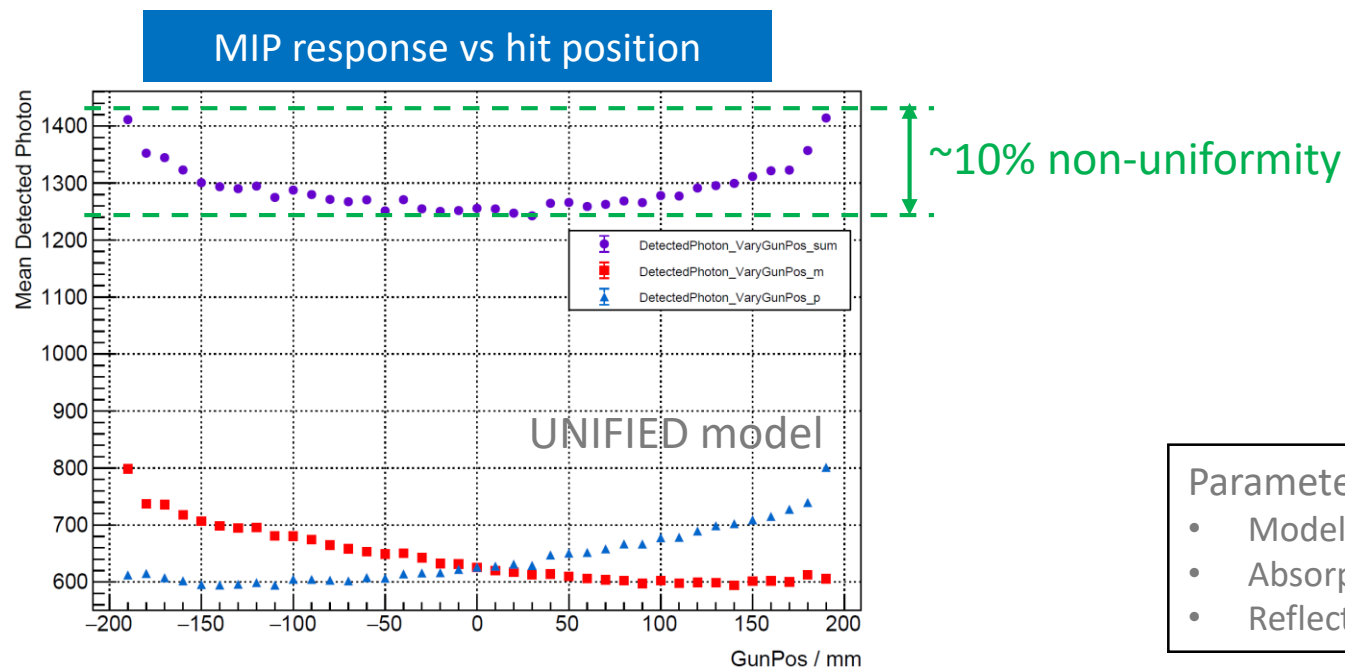
- Geant4 full simulation study
 - Response uniformity of a single crystal bar
 - 2D uniformity scan of crystal module
 - Non-uniformity: Impact on energy resolution
- Characterizations of crystals and SiPMs
 - SiPM calibration with picosecond laser
 - Uniformity scan with 400 mm BGO crystal bar
- Small-scale detector module design: first glance



- Geant4 optical simulation
 - A single BGO crystal bar wrapped with ESR reflector
- Physics processes
 - Scintillating & Cherenkov
 - Boundary processes and absorption
 - SiPM modelling: geometry and response (PDE)



- Over 1000 photons detected in a single crystal bar
- ~10% non-uniformity under the current simulation parameters
- Simply described by a quadratic function



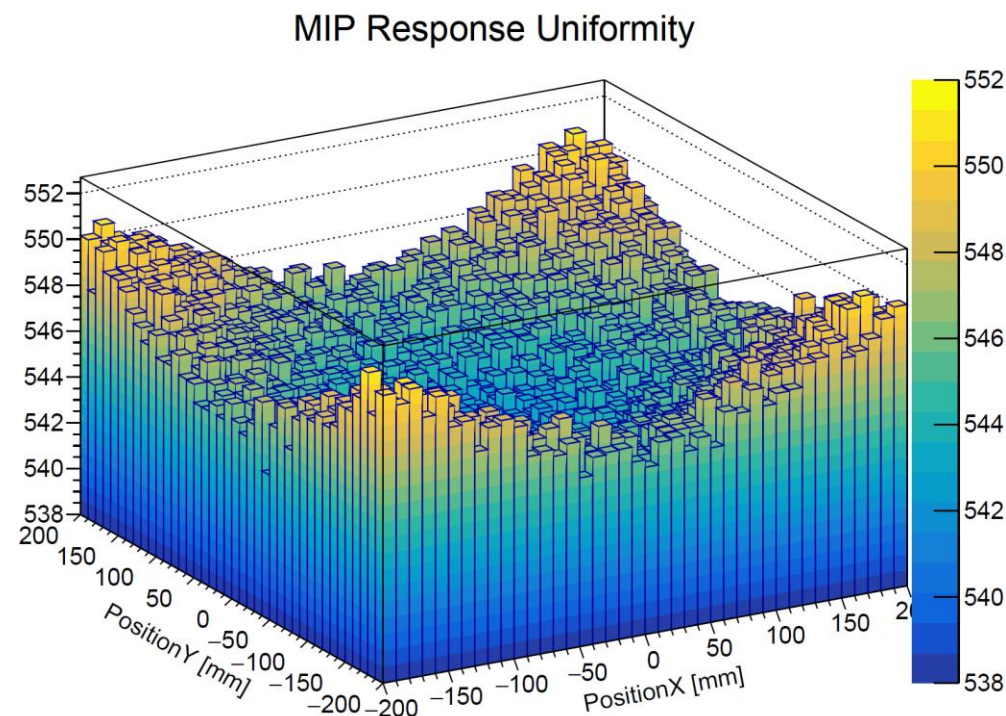
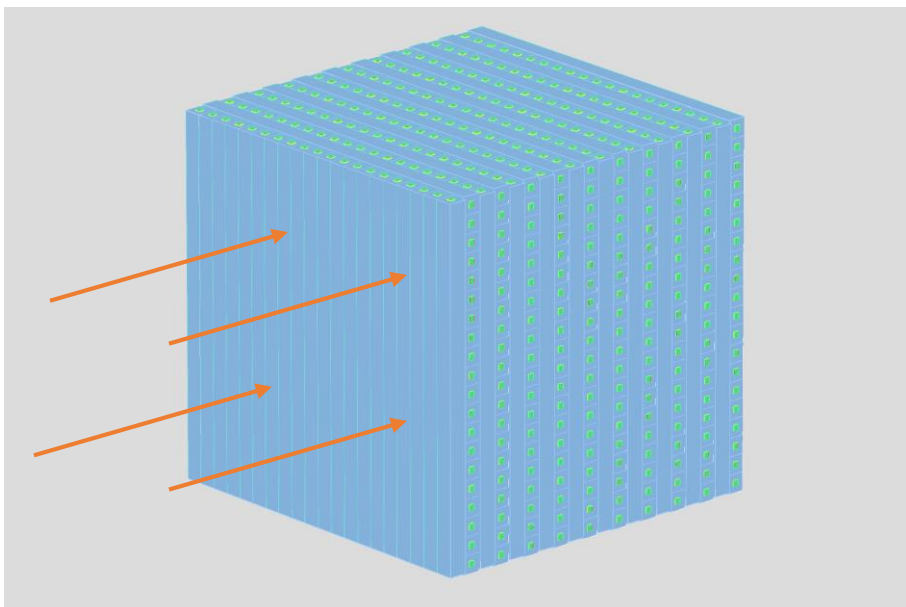
Parameters

- Model: UNIFIED, with adjustable surface roughness
- Absorption length, emission spectrum: measured data
- Reflectivity, Rindex, SiPM PDE...: available data from documentations



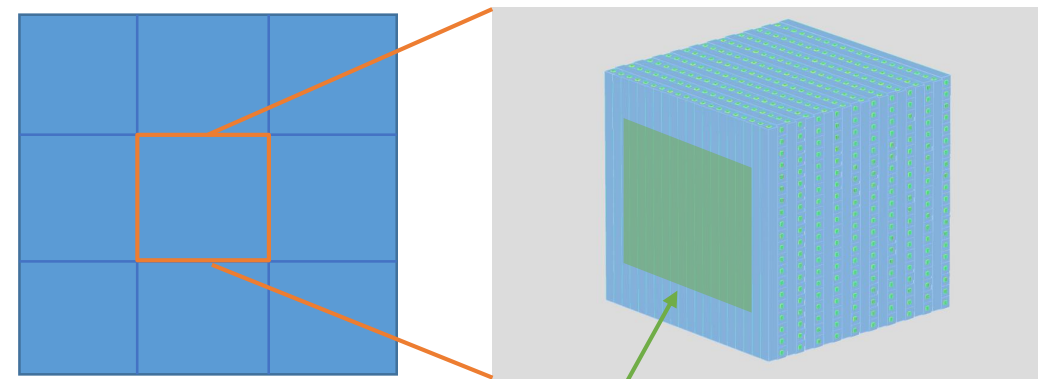
- Simulation setup

- $10 \times 10 \times 400$ mm³ BGO crystal Bar
- Crossed bar, $40 \times 40 \times 60$ module
- 1 GeV muon, 2D uniformity scan
- Response has been parameterized (simulated without optical process)

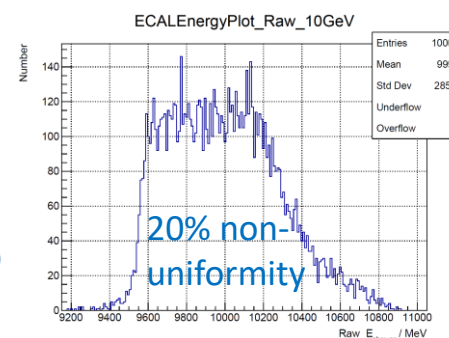
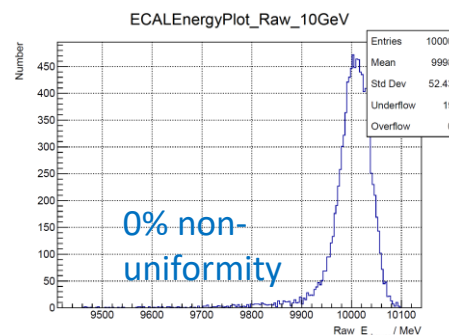
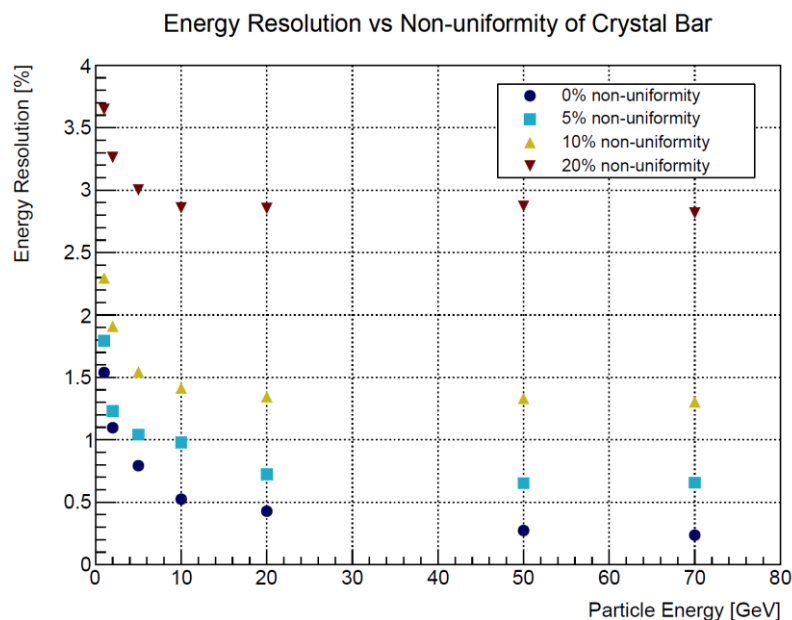


- MIP Response of four corners is higher
- 2D non-uniformity seems lower than 10%
- Calibration constants depend on hit positions
 - Good reconstruction algorithm is required

- Impact on energy resolution
 - 1-100 GeV electron
 - 3×3 modules are used to prevent energy leakage
 - Digitization and energy calibration have been implemented
 - Energy resolution = Mean/StdDev



Incident particles randomly hit this area of the middle module



- For higher value of non-uniformity, the distribution of energy tends to be non-Gaussian
- Severe distortion of energy resolution
- Response non-uniformity of a single crystal bar need to be considered



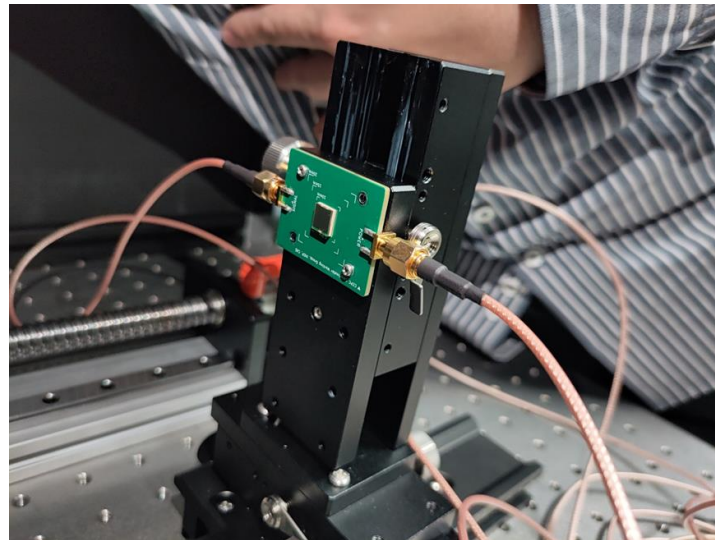
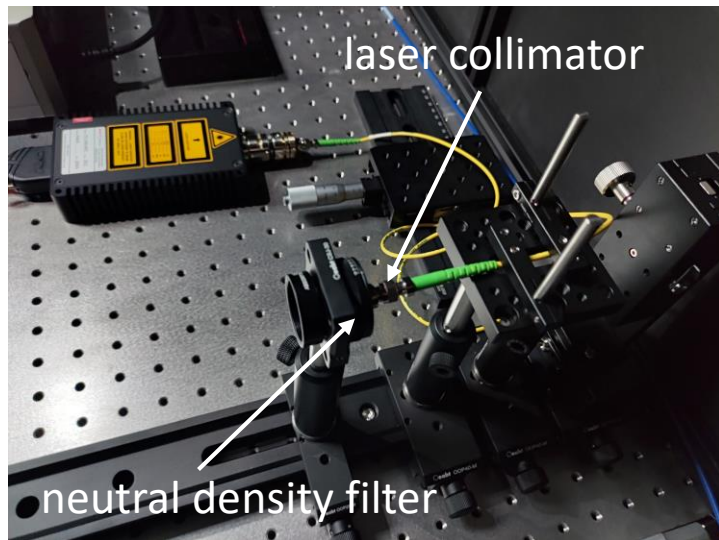
Development of crystal ECAL:

- Geant4 full simulation study
 - Response uniformity of a single crystal bar
 - 2D uniformity scan of crystal module
 - Non-uniformity: Impact on energy resolution
- **Characterizations of crystals and SiPMs**
 - **SiPM calibration with picosecond laser**
 - **Uniformity scan with 400 mm BGO crystal bar**
- Small-scale detector module design: first glance



Characterizations of crystals and SiPMs: laser calibration of SiPMs

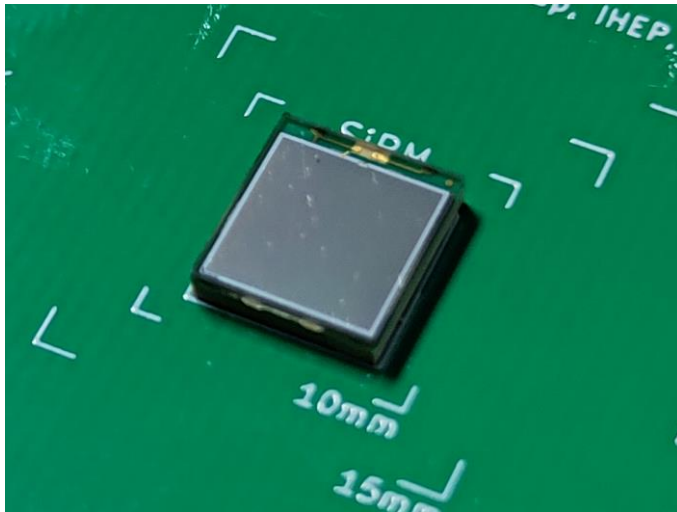
- Test stand setup
 - 405nm picosecond laser
 - Pulse width typically < 60 ps
 - Timing jitter < 3 ps rms
 - 0.1% transmittance neutral density filter to reduce laser intensity
 - Laser collimation: spot diameter < 1 mm
 - Preamplifier with adjustable gain



Characterizations of crystals and SiPMs: laser calibration of SiPMs

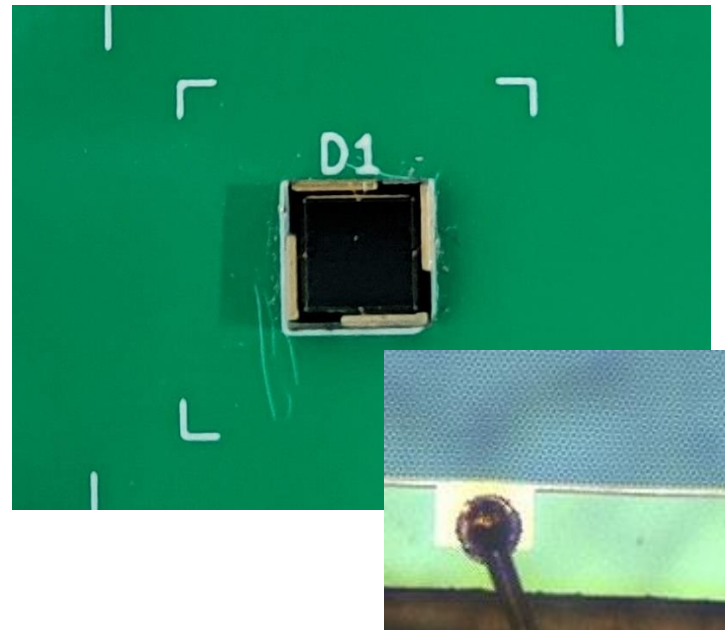
- DUT: HPK & NDL SiPMs

HPK S13360-6025PE



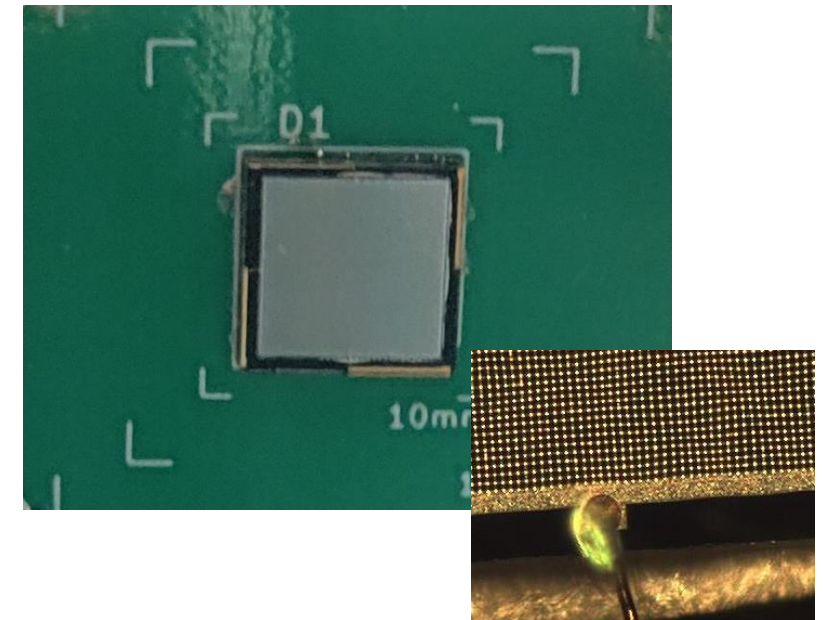
- $6 \times 6 \text{ mm}^2$
- $25 \mu\text{m pixel} \times 57600$
- Nominal gain 7×10^5

NDL EQR06 11-3030D-S



- $3 \times 3 \text{ mm}^2$
- $6 \mu\text{m pixel} \times 244720$
- Nominal gain 8×10^4

NDL EQR15 11-6060D-S

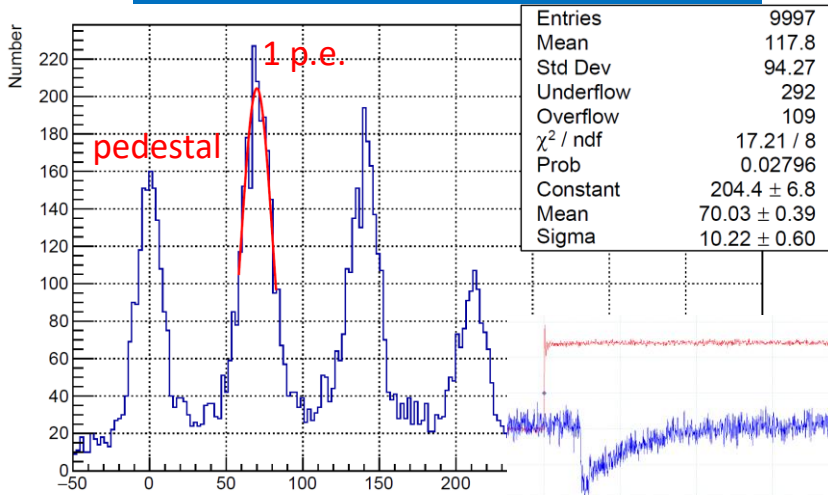


- $6 \times 6 \text{ mm}^2$
- $15 \mu\text{m pixel} \times 160000$
- Nominal gain 4×10^5

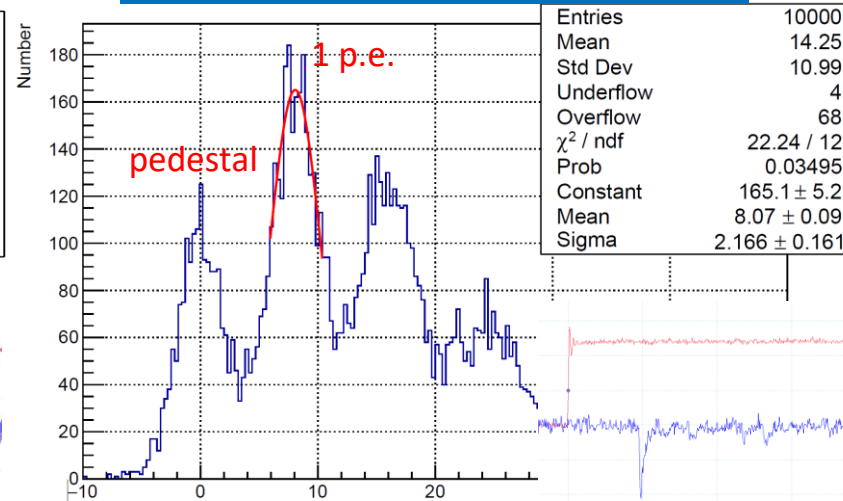
Characterizations of crystals and SiPMs: laser calibration of SiPMs

- Single photon spectrum

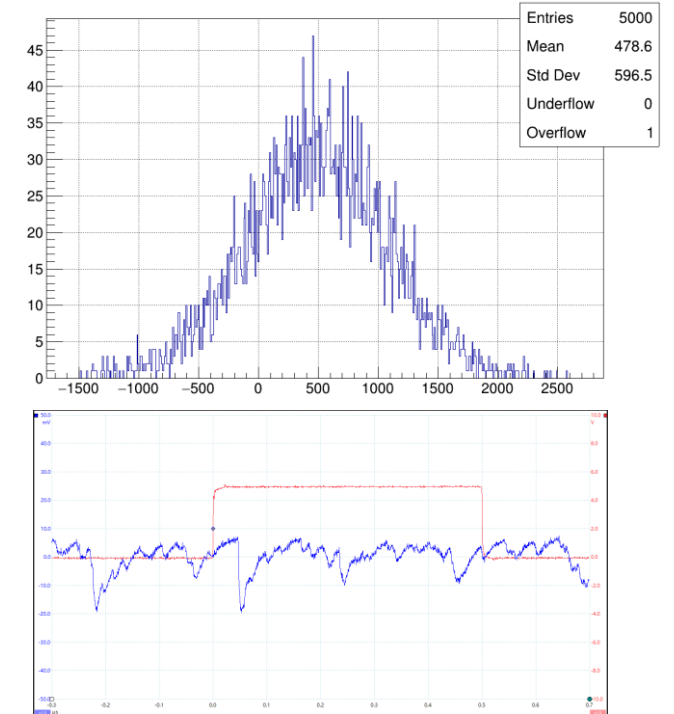
HPK S13360-6025PE



NDL EQR06 11-3030D-S



NDL EQR15 11-6060D-S



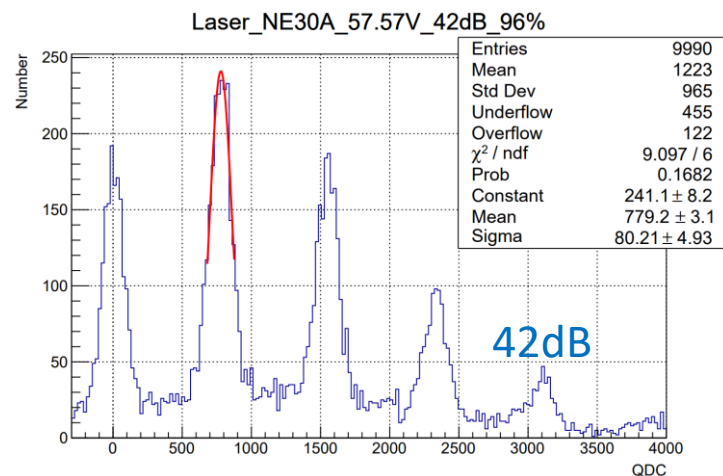
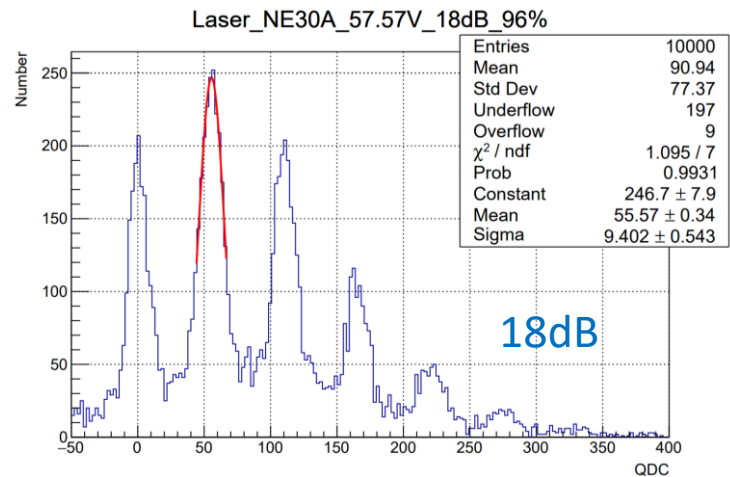
- Gain crosscheck: HPK S13360-6025PE vs NDL EQR06 11-3030D-S
 - $7 \times 10^5 / 8 \times 10^4 \approx 70.03 / 8.07$
- NDL EQR06 11-3030D-S
 - More pixels, narrower pulse shape
 - Worse single photon peak resolution
- Criteria for SiPMs: pixel size / gain / capability of single photon detection...

- Too many thermal noise signals
- Unstable baseline
- Unable to perform single photon calibration

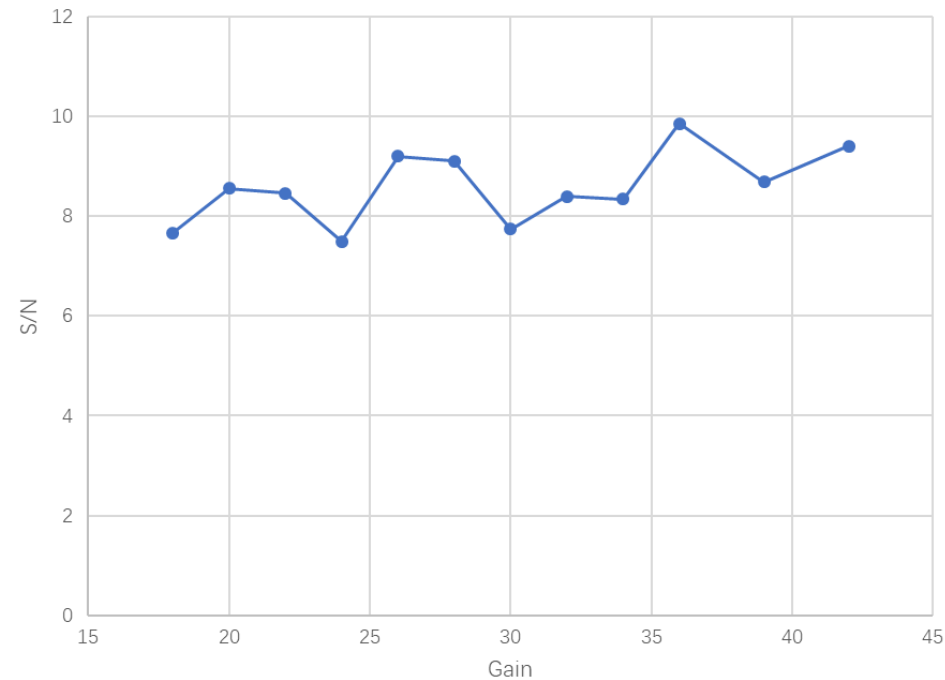


Characterizations of crystals and SiPMs: laser calibration of SiPMs

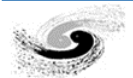
- S/N versus gain of preamplifier



$$S/N = \frac{\text{Mean}_{1p.e.}}{\text{Sigma}_{pedestal}}$$

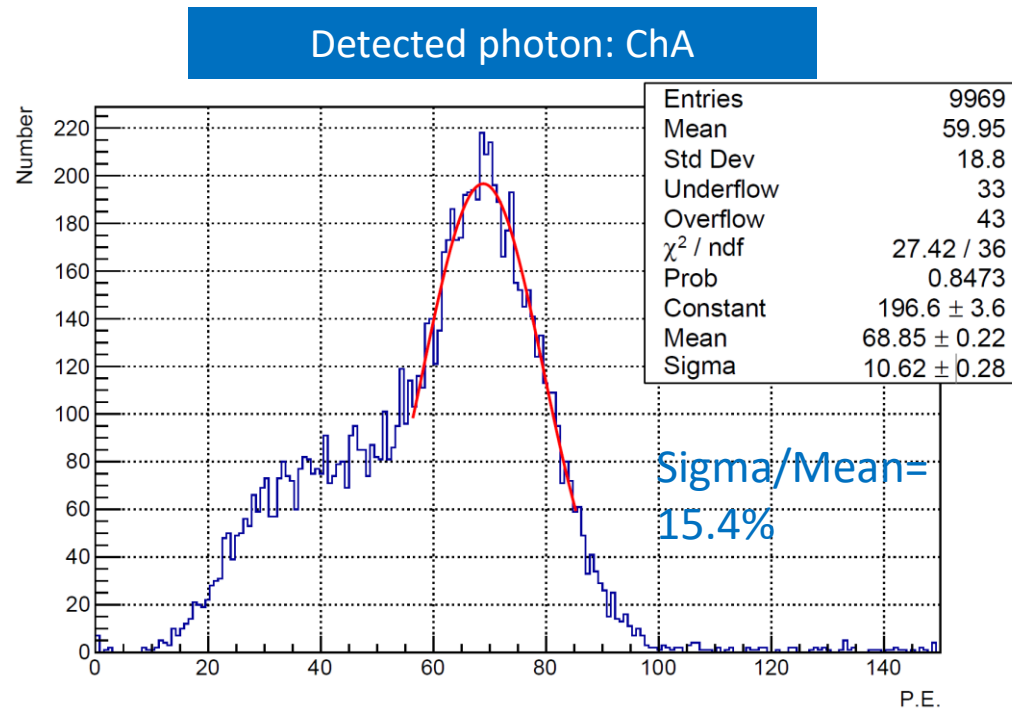


- S/N did not change significantly from 18 dB to 42 dB
- Operation under low gain can increase the dynamic range

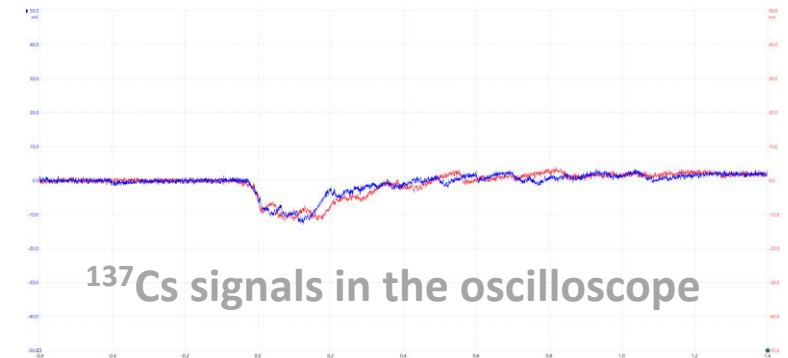
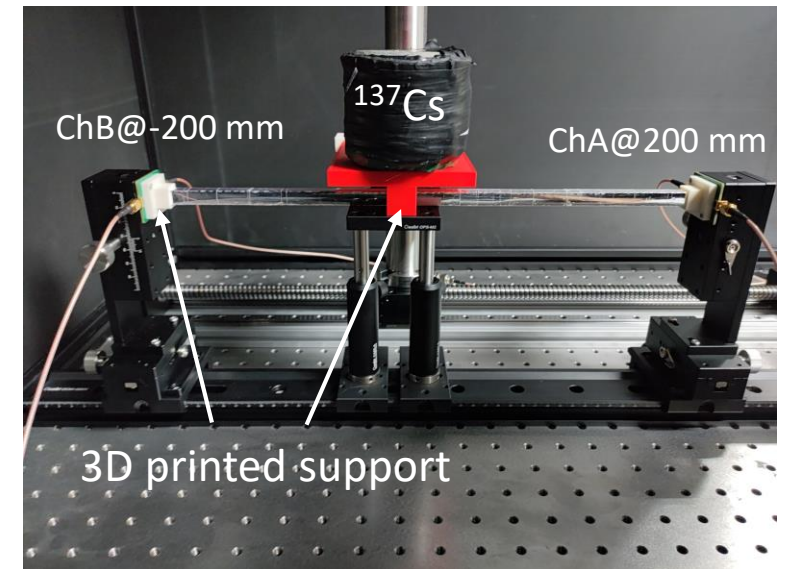


Characterizations of crystals and SiPMs: radioactive source test of BGO crystal

- Uniformity scan: 662keV gamma from ^{137}Cs , change hit positions
 - $400 \times 10 \times 10 \text{ mm}^3$ BGO crystal bar, ESR wrapping
 - $6 \times 6 \text{ mm}^2$ SiPMs, air coupling
 - Fit the 662keV photopeak to get corresponding #photons

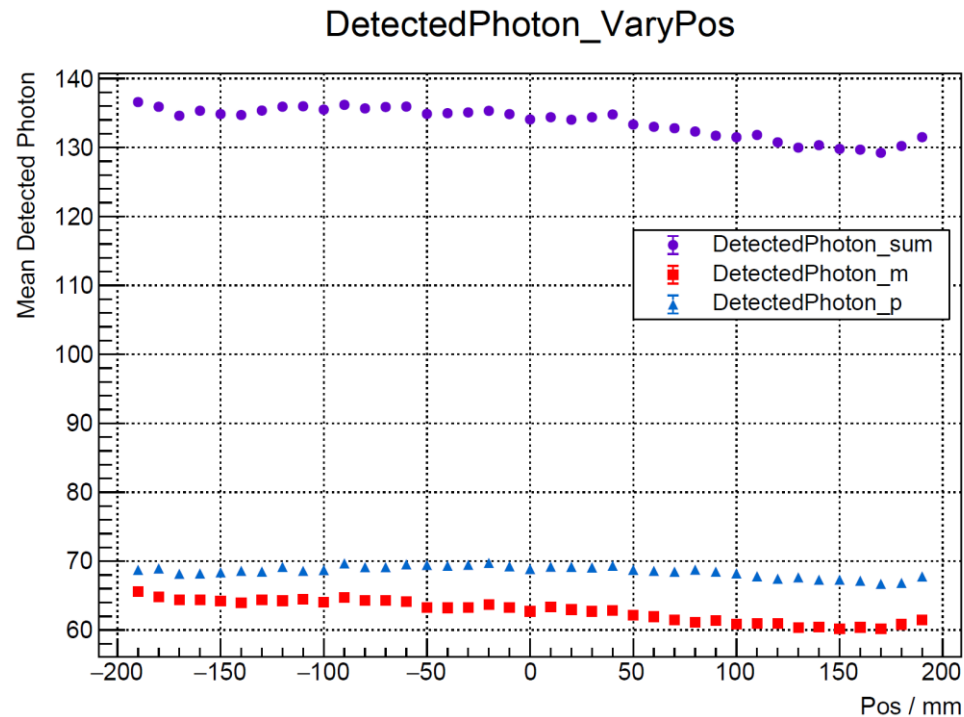


- Energy resolution for 662keV photon: 15.4%

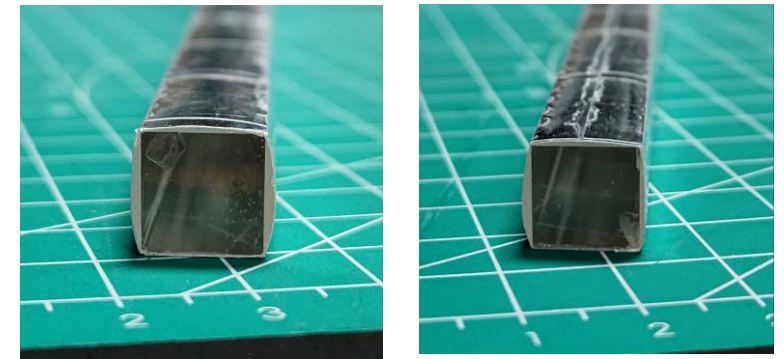
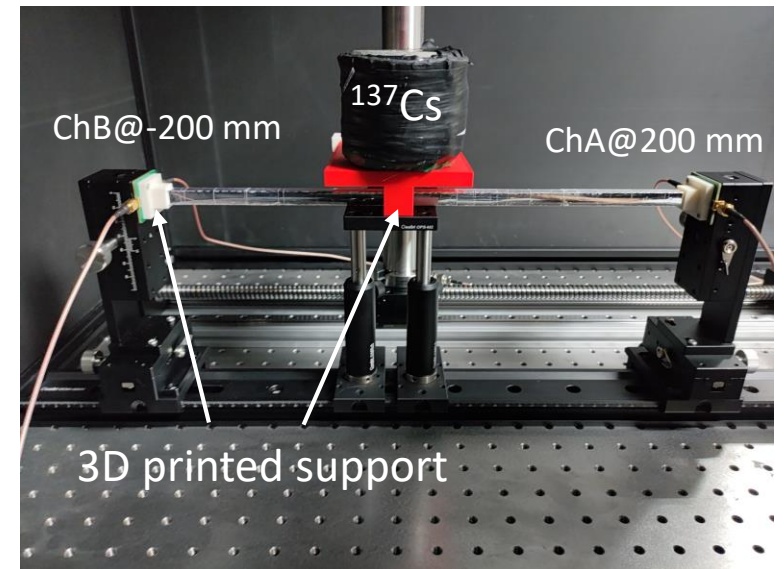


Characterizations of crystals and SiPMs: radioactive source test of BGO crystal

- Uniformity scan: 662keV gamma for ^{137}Cs , change hit positions



- Attenuation effect seems different than expected in simulation, relatively low response near one side
- Potential factors related to crystal manufacture
 - Light yield / transmittance difference along the direction of crystal growth
 - Difference between the surfaces of two ends



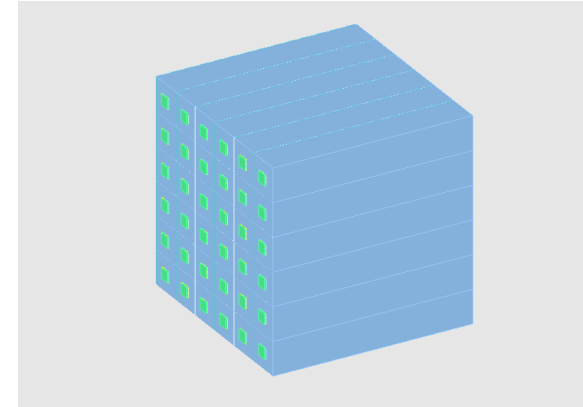
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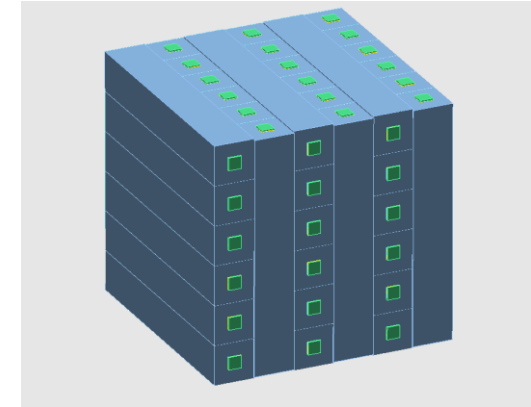


Small-scale detector module design: first glance

- Motivations: crystal module development
 - EM shower profiles are intrinsically compact
 - e.g. $R_M = 2.26$ cm for BGO
 - Small-scale modules is sufficient for EM showers
 - Crucial to have beam tests for system level studies
 - Identify critical questions/issues for the final detector
 - Evaluate performance with data and to validate simulation
- Geant4 simulation studies
 - Crystal module ($12 \times 12 \times 12$ cm³)
 - 6×6 crystal matrix (36 ch ASIC readout)
 - 6 layers of crystal bar with crossed arrangement, double-sided readout (4×18 ch ASIC readout)
 - Beam test setup:
 - Use two modules to provide sufficient longitudinal depth ($21.4 X_0$)



6×6 crystal matrix



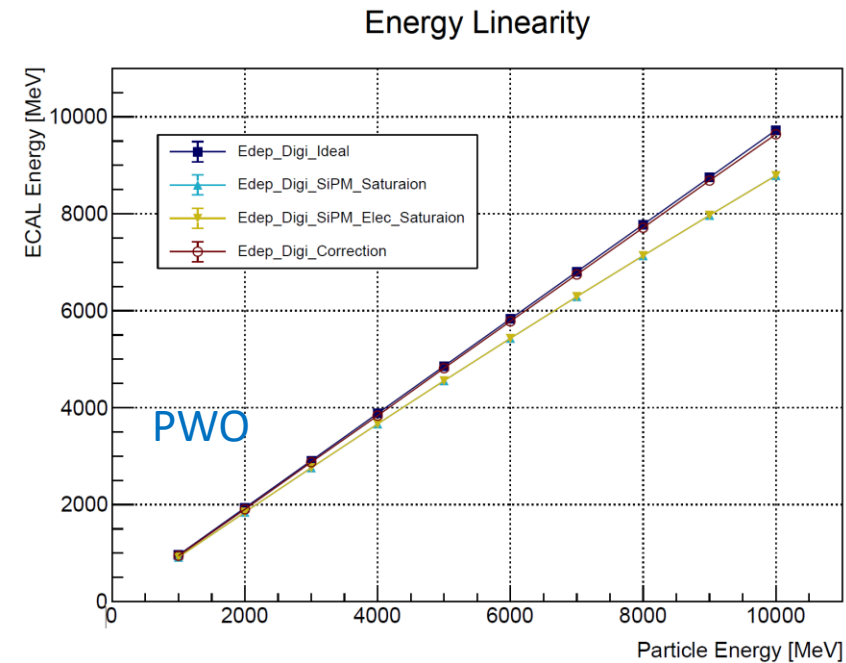
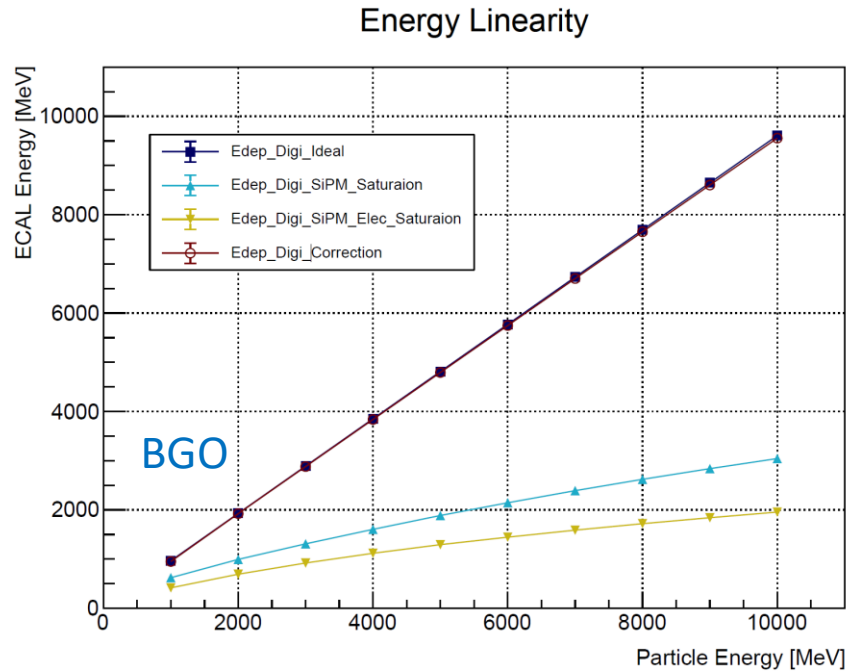
crossed crystal bar



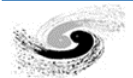
A dummy crystal matrix with 3D printed support structure

Small-scale detector module design: first glance

- Simulation of BGO/PWO crystal matrix for beam test



- DESY: 1-6 GeV electrons; CERN PS: 1-15 GeV muons/electrons/hadrons
- Saturation effects: severely degrade energy linearity (as well as resolution)
- Deal with saturation
 - Adjust the fluorescence property of BGO crystal (collaboration with SIC, CAS), neutral density filter, Si-PIN photodiode...
- Realistic mechanical and electronic design



- Geant4 full simulations
 - Response uniformity from single crystal bar to ECAL module
- Measurements on SiPMs and crystals
 - SiPM laser calibration, radioactive source test and cosmic-ray test
- Small-scale detector module design
 - Preparing for beam test, still many issues to be addressed

